2-input OR Gate

HITACHI

ADE-205-330E (Z)

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Description

The HD74LV1GT32A is high speed CMOS two input OR gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output. Low voltage and high speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

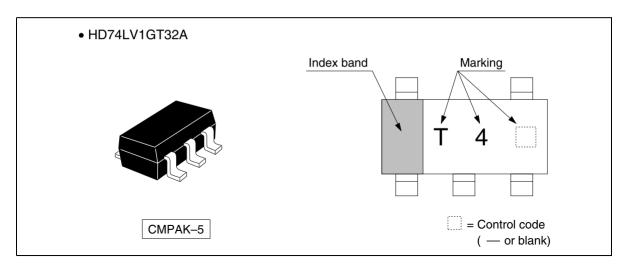
Features

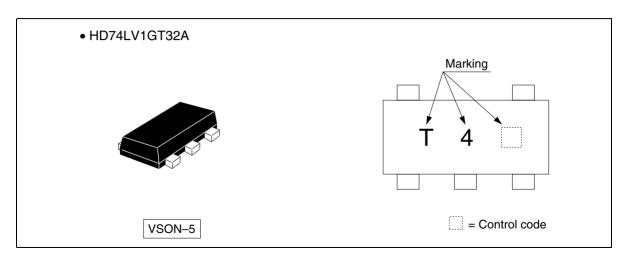
- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- TTL compatible input level. Supply voltage range: 4.5 to 5.5 V Operating temperature range: -40 to +85°C
- All inputs V_{H} (Max.) = 5.5 V (@ V_{CC} = 0 V to 5.5 V) All outputs V_{O} (Max.) = 5.5 V (@ V_{CC} = 0 V)
- Output current $\pm 12 \text{ mA}$ (@V_{cc} = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.
- Package type

Package type	Package code	Package suffix	Taping code
CMPAK-5 pin	CMPAK-5	СМ	E (3,000 pcs / Reel)
VSON-5 pin	TNP-5D	VS	E (3,000 pcs / Reel)



Outline and Article Indication



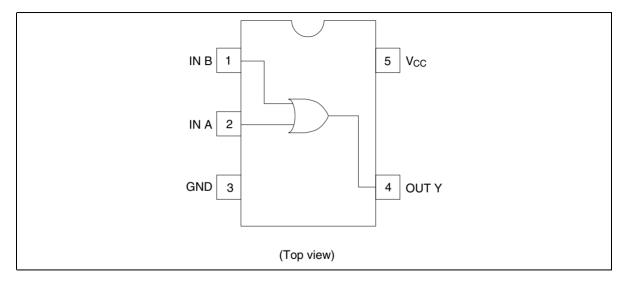


Function Table

Inputs		Output Y
A	В	
L	L	L
Н	L	Н
L	Н	Н
Н	Н	Н

H : High level L : Low level

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{cc}	–0.5 to 7.0	V	
Input voltage range *1	V _I	-0.5 to 7.0	V	
Output voltage range *1,2	V _o	-0.5 to V_{cc} + 0.5	V	Output : H or L
		-0.5 to 7.0		V _{cc} : OFF
Input clamp current	I _{IK}	-20	mA	V ₁ < 0
Output clamp current	I _{ok}	±50	mA	$V_{o} < 0 \text{ or } V_{o} > V_{cc}$
Continuous output current	Io	±25	mA	$V_o = 0$ to V_{cc}
Continuous current through V_{cc} or GND	I _{CC} or I _{GND}	±50	mA	
Maximum power dissipation at Ta = 25°C (in still air) ³	P _T	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes:

The absolute maximum ratings are values which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V _{cc}	4.5	5.5	V	
Input voltage range	V _i	0	5.5	V	
Output voltage range	V _o	0	V _{cc}	V	
Output current	I _{OH}	_	12	mA	V _{cc} = 4.5 to 5.5 V
	I _{OL}	_	-12	mA	V _{cc} = 4.5 to 5.5 V
Input transition rise or fall rate	Δt / Δν	0	20	ns / V	V _{cc} = 4.5 to 5.5 V
Operating free-air temperature	T _a	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristic

• $Ta = -40 \text{ to } 85^{\circ}\text{C}$

Item	Symbol	V _{cc} (V) *	Min	Тур	Max	Unit	Test condition
Input voltage	V _{IH}	4.5 to 5.5	2.0	_	_	V	
	V _{IL}	4.5 to 5.5	_	_	0.8		
Hysteresis voltage	V _H	5.0	_	0.15	_	V	$V_T^+ - V_T^-$
Output voltage	V _{OH}	Min to Max	V _{cc} -0.1	_	_	V	$I_{OH} = -50 \mu A$
		4.5	3.8	_	_		$I_{OH} = -12 \text{ mA}$
	V _{OL}	Min to Max	_	_	0.1		$I_{OL} = 50 \mu A$
		4.5	_	_	0.55		I _{OL} = 12 mA
Input current	I _{IN}	0 to 5.5	_	_	±1	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Quiescent supply current	I _{cc}	5.5	_	_	10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_{O} = 0$
	ΔI_{cc}	5.5	_	_	1.5	mA	One input $V_{IN} = 3.4 \text{ V}$, other input V_{CC} or GND
Output leakage current	I _{OFF}	0	_	_	5	μΑ	V_1 or $V_0 = 0$ to 5.5 V
Input capacitance	C _{IN}	5.0	_	2.5	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

• $V_{CC} = 5.0 \pm 0.5 \text{ V}$

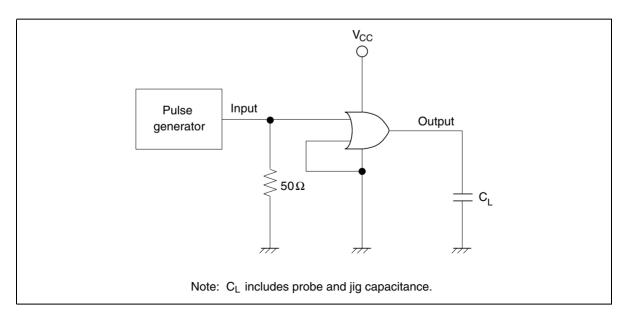
Item	Symbol	Ta = 25°C		Ta = -40 to 85°C U		Unit	Test	FROM	то	
		Min	Тур	Max	Min	Max	_	Conditions	(Input)	(Output)
Propagation	t _{PLH}	_	5.0	6.9	1.0	8.0	ns	C _L = 15 pF	A or B	Υ
delay time	$t_{\scriptscriptstylePHL}$	_	5.5	7.9	1.0	9.0	_	C _∟ = 50 pF	_	

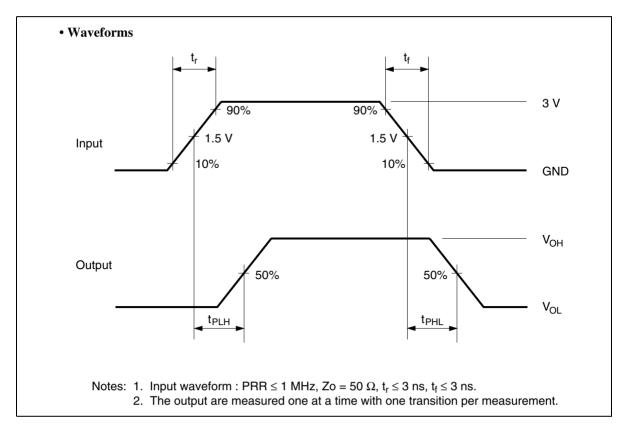
Operating Characteristics

• $C_r = 50 pF$

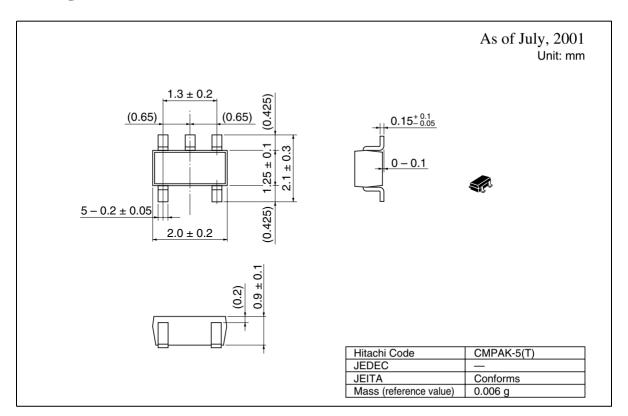
Item	Symbol	V _{cc} (V)	Ta = 2	Ta = 25°C			Test Conditions		
			Min	Тур	Max				
Power dissipation capacitance	C_{\scriptscriptstylePD}	5.0	_	11.5	_	pF	f = 10 MHz		

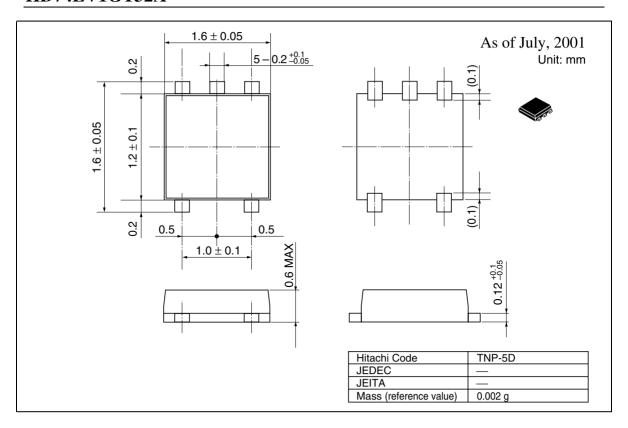
Test Circuit





Package Dimensions





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